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PCIe M.2 SSDs PCIe SSD 110S & 112S

Transcend's PCIe SSD 110S/112S utilizes the PCI Express® Gen3 x4 interface supported by the latest NVMe[™] standard, to unleash next-generation performance. The PCIe SSD 110S/112S aims at high-end applications, such as digital audio/video production, gaming, and enterprise use, which require constant processing heavy workloads with no system lags or slowdowns of any kind. Powered by 3D NAND flash memory, the PCIe SSD 110S/112S gives you not only fast transfer speeds but unmatched reliability.



Compelling performance for highend applications

Transcend's PCIe SSD 110S/112S follows NVMe 1.3 and utilizes the PCIe[™] Gen3 x4 interface, meaning four lanes are used for transmitting and receiving data simultaneously, resulting in compelling performance of up to 1,700MB/s read and 1,400MB/s write.

Note: Performance is based on CrystalDiskMark v5.0.2.



3D expansion to break through limits

Unlike the existing planar NAND chips, 3D NAND flash is a type of flash memory in which the memory cells are stacked vertically in multiple layers. 3D NAND is developed to break through density limitations of the 2D planar NAND, and thus can deliver a greater level of performance and endurance.



Better endurance, higher reliability

Transcend's PCIe SSD 110S/112S is engineered with LDPC (Low-Density Parity Check) coding, a powerful ECC algorithm, to keep data secure. Manufactured with high-quality NAND flash chips, and engineered dynamic thermal throttling mechanism, the PCIe SSD 110S/112S guarantees superior endurance and stability for high-end applications.

Transcend[®]



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Features

- Uses PCIe Gen3 x4 interface and meets NVMe 1.3 standard
- Up to 1,700 MB/s read; 1,400 MB/s write
- 3D NAND flash memory



SSD Scope

SSD Scope features useful functions to maintain your SSD in a healthy status and also copy data from your original HDD to Transcend's new SSD.

Specification

Appearance	
Dimensions	Single-sided: 80 mm x 22 mm x 2.23 mm (3.15" x 0.87" x 0.09") Double-sided: 80 mm x 22 mm x 3.58 mm (3.15" x 0.87" x 0.14")
Weight	8 g (0.28 oz)
М.2 Туре	2280-S2-M (Single-sided) 2280-D2-M (Double-sided)
Interface	
Bus Interface	NVMe PCle Gen3 x4
Storage	
Flash Type	3D NAND flash
Capacity	128 GB / 256 GB / 512 GB / 1 TB
Operating Environment	
Operating Temperature	0°C (32°F) ~ 70°C (158°F)
Operating Voltage	3.3V±5%
Performance	
Sequential Read/Write (CrystalDiskMark, max.)	Read: up to 1,700 MB/s Write: up to 1,400 MB/s
4K Random Read/Write (IOmeter, max.)	Read: up to 160,000 IOPS Write: up to 140,000 IOPS
Mean Time Between Failures (MTBF)	2,000,000 hour(s)
Drive Writes Per Day (DWPD)	0.2 (5 yrs)
Terabytes Written (Max.)	400 TBW
Warranty	
Certificate	CE / FCC / BSMI / KC / RCM
Warranty	Five-year Limited Warranty

Ordering Information

128GB	TS128GMTE110S
256GB	TS256GMTE110S
512GB	TS512GMTE110S
512GB	TS512GMTE112S
1TB	TS1TMTE110S
1TB	TS1TMTE112S